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2 Port, USB 2.0 High Speed (480 Mbps) Switch, DPDT Analog Switch

DESCRIPTION

The DG2722 is 2 port high speed analog switch optimized for USB 2.0 signal switching. The DG2722 switch is configured in DPDT. It handles bidirectional signal flow, achieving a 900 MHz - 3 dB bandwidth, and a port to port crosstalk and isolation at - 49 dB.

Processed with high density sub micron CMOS, the DG2722 provide low parasitic capacitance. Signals are routed with minimized phase distortion and attain a bit to bit skew is as low as 40 pS.

The DG2722 is designed for a wide range of operating voltages, from 2.7 V to 4.3 V that can be driven directly from one cell Li-ion battery. On-chip circuitry protects against conditions when either the D+/D- lines are shorted to the V_{BUS} at the USB port. Additionally, logic control pins (S and \overline{OE}) can tolerate the presence of voltages that are above the supply power rail (V+). The control logic threshold is guaranteed to be (V_{IH} = 1.3 V/min). Latch up current is 300 mA, as per JESD78, and its ESD tolerance exceeds 8 kV.

Packaged in ultra small miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm), it is ideal for portable high speed mix signal switching application.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device termination. The miniQFN-10 package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix to the ordering part number. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL rating.

As a further sign of Vishay Siliconix's commitment, the DG2722 is fully RoHS complaint.

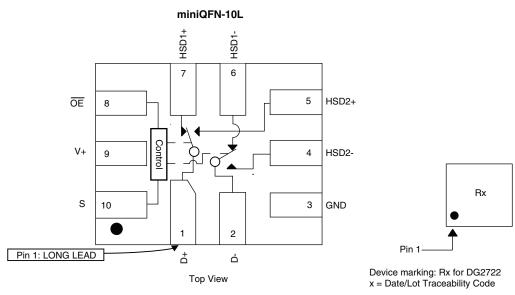
FEATURES

- Wide operation voltage range
- Low on-resistance, 7 Ω (typical at 3 V)
- Low capacitance, 5.6 pF (typical)
- 3 dB high bandwidth: 900 MHz (typical)
- Low bit to bit skew: 40 pS (typical)
- Low power consumption
- Low logic threshold: V
- Power down protection: D+/D- pins can tolerate up to 5 V when V+ = 0 V
- Logic (S and OE) above V+ tolerance
- 8 kV ESD protection (HBM)
- Latch-up current 300 mA per JESD78
- Lead (Pb)-free low profile miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm)

APPLICATIONS

- · Cellular phones
- Portable media players
- PDA
 - Digital camera
 - GPS
 - Notebook computer
 - TV, monitor, and set top box











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ORDERING INFORMATION					

Temp. Range	Package	Part Number
- 40 °C to 85 °C	miniQFN-10	DG2722DN-T1-E4

TRUTH TABLE						
OE (Pin 8)	S (Pin 10)	Function				
0	0	D+ = HSD1+ and D- = HSD1-				
0	1	D+ = HSD2+ and D- = HSD2-				
1	Х	Disconnect				

PIN DESCRIPTIONS					
Pin Name	Description				
ŌĒ	Bus Switch Enable				
S	Select Input				
HSD1±, HSD2±, D±	Data Port				

Parameter		Limit	Unit	
Reference to GND	V+	- 0.3 to 5.0	V	
	S, OE, D±, HSD1±, HSD2± ^a	- 0.3 to (V+ + 0.3)	v	
Current (Any Terminal except S, OE, D±, HSD1±, HSD2±)		30		
Continuous Current (S, OE, D±, HSD1	±, HSD2±)	± 250	mA	
eak Current (Pulsed at 1 ms, 10 % Duty Cycle)		± 500		
Storage Temperature (D Suffix)		- 65 to 150	°C	
Power Dissipation (Packages) ^b	miniQFN-10 ^c	208	mW	
ESD (Human Body Model) I/O to GND	8	kV		
Latch-up (Current Injection)		300	mA	

a. Signals on S, OE, D±, HSD1±, HSD2± exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 2.6 mW/°C above 70 °C.

SPECIFICATIONS V+ = 3.0 V								
		Test Conditions		Limits - 40 °C to 85 °C				
Parameter	Symbol	Otherwise Unless Specified	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit	
Analog Switch	•							
Analog Signal Range ^d	V _{ANALOG}	R _{DS(on)}	Full	0		V+	V	
On-Resistance	R _{DS(on)}	V+ = 3.0 V, I _{D±} = 8 mA, V _{HSD1/2±} = 0.4 V	Room		7	8		
On-nesistance	US(on)	$v_{\pm} = 0.0 v_{\pm} n_{D\pm} = 0 m_{A}, v_{HSD1/2\pm} = 0.4 v_{\pm}$	Full			9		
On-Resistance Match ^d	ΔR_{ON}	V+ = 3.0 V, $I_{D\pm}$ = 8 mA, $V_{HSD1/2\pm}$ = 0.4 V	Room		0.8		Ω	
On-Resistance Resistance Flatness ^d	R _{ON} Flatness	V+ = 3.0 V, $I_{D\pm}$ = 8 mA, $V_{HSD1/2\pm}$ = 0.0 V, 1.0 V	Room		2.0			
Switch Off Leakage Current	I _(off)	V+ = 4.3 V, V _{HSD1/2±} = 0.3 V, 3.0 V, V _{D±} = 3.0 V, 0.3 V	Full	- 100		100		
Channel On Leakage Current	I _(on)	V+ = 4.3 V, V _{HSD1/2±} = 0.3 V, 4.0 V, V _{D±} = 4.0 V, 0.3 V	Full	- 200		200	nA	
Digital Control						•		
Innut Voltogo Lligh	V	V+ = 3.0 V to 3.6 V	Full	1.3				
Input Voltage High	V _{INH}	V+ = 4.3 V	Full	1.5			v	
Input Voltage Low	V _{INL}	V+ = 3.0 V to 4.3 V	Full			0.5		
Input Capacitance	C _{IN}		Full		5.6		pF	
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	- 1		1	μA	



DG2722

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SPEC	FICAT	IONS	V+ = 3.0) V (

		Test Conditions		Limits - 40 °C to 85 °C			
Parameter	Symbol	Otherwise Unless Specified	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit
Dynamic Characteristics		•					
Break-Before-Make Time ^{e, d}	t _{BBM}		Room Full		5		
Enable Turn-On Time ^{e, d}	t _{ON(EN)}	V+ = 3.0 V, V _{D1/2 ±} = 1.5 V, R _L = 50 Ω, C _L = 35 pF	Room			30	ns
Enable Turn-Off Time ^{e, d}	t _{OFF(EN)}		Room			25	
Charge Injection ^d	Q _{INJ}	C _L = 1 nF, R _{GEN} = 0 Ω, V _{GEN} = 0 V	Full		0.5		рС
Off-Isolation ^d	OIRR	V+ = 3.0 V to 3.6 V, R _L = 50 Ω , C _L = 5 pF, f = 240 MHz		-	- 30		dB
Crosstalk ^d	X _{TALK}				- 45		
Bandwidth ^d	BW	V+ = 3.0 V to 3.6 V, R_L = 50 Ω , - 3 dB	-		900		MHz
Channel-Off Capacitance ^d	C _{D1± (off)}	- V+ = 3.3 V, f = 1 MHz	Room		1.3		pF
	C _{D2± (off)}				1.3		
Channel-On Capacitance ^d	$C_{D\pm (off)}$				2.7		
Channel-On Capachance	C _{D± (on)}				6.5		
Channel-to-Channel Skew ^d	t _{SK(O)}				50		1
Skew Off Opposite Transitions of the Same Output ^d	t _{SK(p)}	V+ = 3.0 V to 3.6 V, R_L = 50 Ω , C_L = 5 pF			20		ps
Total Jitter ^d	tj				200		
Power Supply		·	·				
Power Supply Range	V+			2.6		4.3	V
Power Supply Current	l+	$V_{IN} = 0 V$, or V+	Full			2	μΑ

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

c. Typical values are for design aid only, not guaranteed nor subject to production testing.

d. Guarantee by design, not subjected to production test.

e. V_{IN} = input voltage to perform proper function.

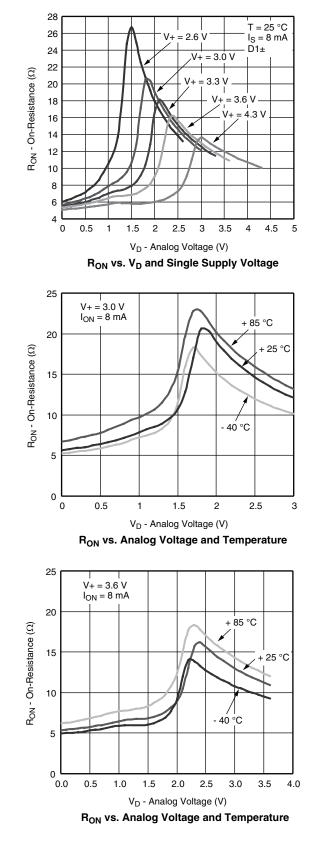
f. Crosstalk measured between channels.

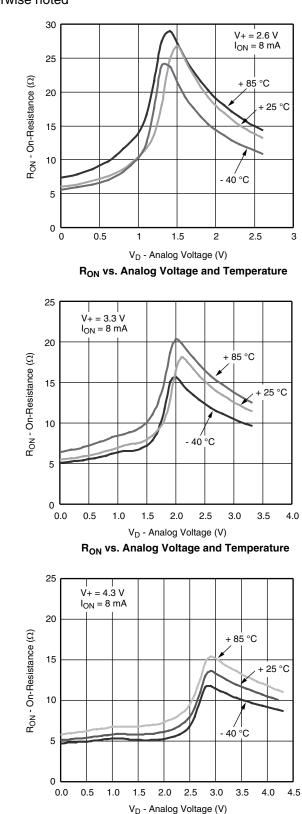
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



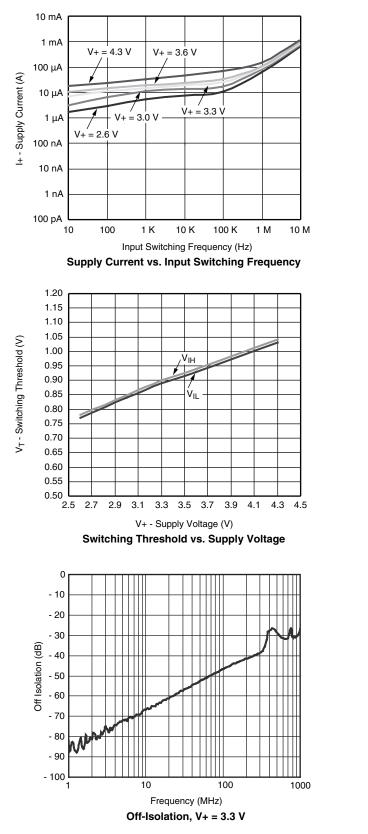


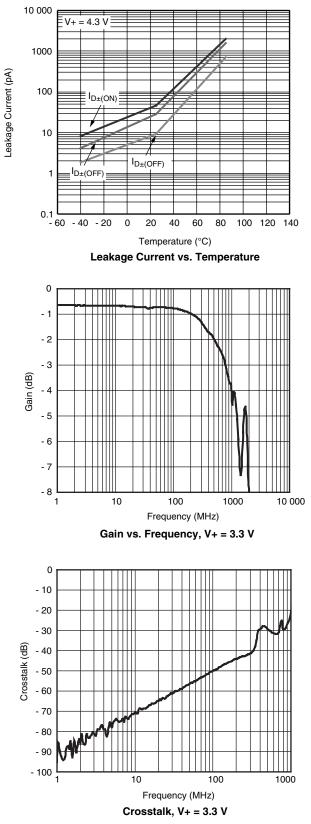
R_{ON} vs. Analog Voltage and Temperature



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TYPICAL CHARACTERISTICS $T_A = 25$ °C, unless otherwise noted



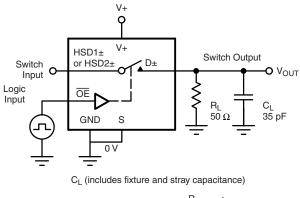


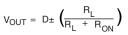
DG2722

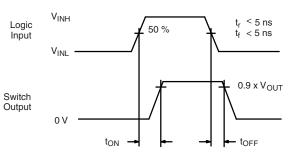
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TEST CIRCUITS

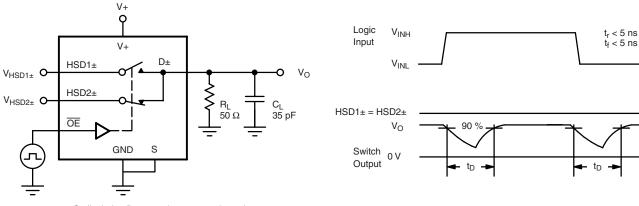






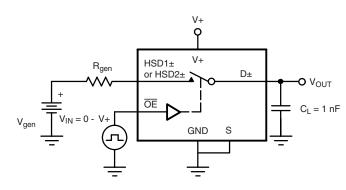
Logic "1" = Switch on Logic input waveforms inverted for switches that have the opposite logic sense.

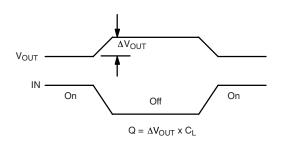




C_L (includes fixture and stray capacitance)







IN depends on switch configuration: input polarity determined by sense of switch.





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TEST CIRCUITS

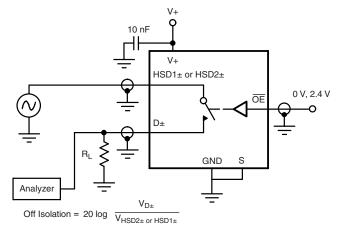


Figure 4. Off-Isolation

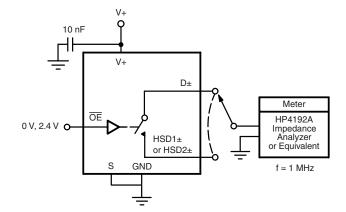


Figure 5. Channel Off/On Capacitance

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